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Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	32MHz
Connectivity	-
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	6
Program Memory Size	3.5KB (2K x 14)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	256 x 8
Voltage - Supply (Vcc/Vdd)	2.3V ~ 5.5V
Data Converters	A/D 4x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	8-VDFN Exposed Pad
Supplier Device Package	8-DFN (3x3)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic12f1612t-i-mf

PIC12(L)F1612/16(L)F1613

TABLE 1-3: PIC16(L)F1613 PINOUT DESCRIPTION

Name	Function	Input Type	Output Type	Description
RA0/AN0/C1IN+/DAC1OUT1/ICSPDAT	RA0	TTL/ST	CMOS/OD	General purpose I/O.
	AN0	AN	—	ADC Channel input.
	C1IN+	AN	—	Comparator positive input.
	DAC1OUT1	—	AN	Digital-to-Analog Converter output.
	ICSPDAT	ST	CMOS	ICSP™ Data I/O.
RA1/AN1/VREF+/C1IN0-/C2IN0-/ZCD1OUT/ICSPCLK	RA1	TTL/ST	CMOS/OD	General purpose I/O.
	AN1	AN	—	ADC Channel input.
	VREF+	AN	—	Voltage Reference input.
	C1IN0-	AN	—	Comparator negative input.
	C2IN0-	AN	—	Comparator negative input.
	ZCD1OUT	—	CMOS	Zero-Cross Detect output.
	ICSPCLK	ST	—	ICSP Programming Clock.
RA2/AN2/C1OUT/T0CKI/CWG1IN/ZCD1IN/INT	RA2	TTL/ST	CMOS/OD	General purpose I/O.
	AN2	AN	—	ADC Channel input.
	C1OUT	—	CMOS/OD	Comparator output.
	T0CKI	TTL/ST	—	Timer0 clock input.
	CWG1IN	TTL/ST	—	CWG complementary input.
	ZCD1IN	AN	—	Zero-Cross Detect input.
	INT	TTL/ST	—	External interrupt.
RA3/VPP/T1G ⁽¹⁾ /T6IN/SMTWIN2/MCLR	RA3	TTL/ST	—	General purpose input with IOC and WPU.
	VPP	HV	—	Programming voltage.
	T1G	TTL/ST	—	Timer1 Gate input.
	T6IN	TTL/ST	—	Timer6 input.
	SMTWIN2	TTL/ST	—	SMT2 window input.
	MCLR	TTL/ST	—	Master Clear with internal pull-up.
RA4/AN3/T1G ⁽¹⁾ /SMTSIG1/CLKOUT	RA4	TTL/ST	CMOS/OD	General purpose I/O.
	AN3	AN	—	ADC Channel input.
	T1G	TTL/ST	—	Timer1 Gate input.
	SMTSIG1	TTL/ST	—	SMT1 signal input.
	CLKOUT	—	CMOS	Fosc/4 output.
RA5/CLKIN/T1CKI/T2IN/CCP2 ⁽¹⁾ /SMTWIN1	RA5	TTL/ST	CMOS/OD	General purpose I/O.
	CLKIN	CMOS	—	External clock input (EC mode).
	T1CKI	TTL/ST	—	Timer1 clock input.
	T2IN	TTL/ST	—	Timer2 input.
	CCP2	TTL/ST	CMOS/OD	Capture/Compare/PWM2.
	SMTWIN1	TTL/ST	—	SMT1 window input.
RC0/AN4/C2IN+	RC0	TTL/ST	CMOS/OD	General purpose I/O.
	AN4	AN	—	ADC Channel input.
	C2IN+	AN	—	Comparator positive input.

Legend: AN = Analog input or output CMOS = CMOS compatible input or output OD = Open-Drain
TTL = TTL compatible input ST = Schmitt Trigger input with CMOS levels I²C = Schmitt Trigger input with I²C levels
HV = High Voltage XTAL = Crystal

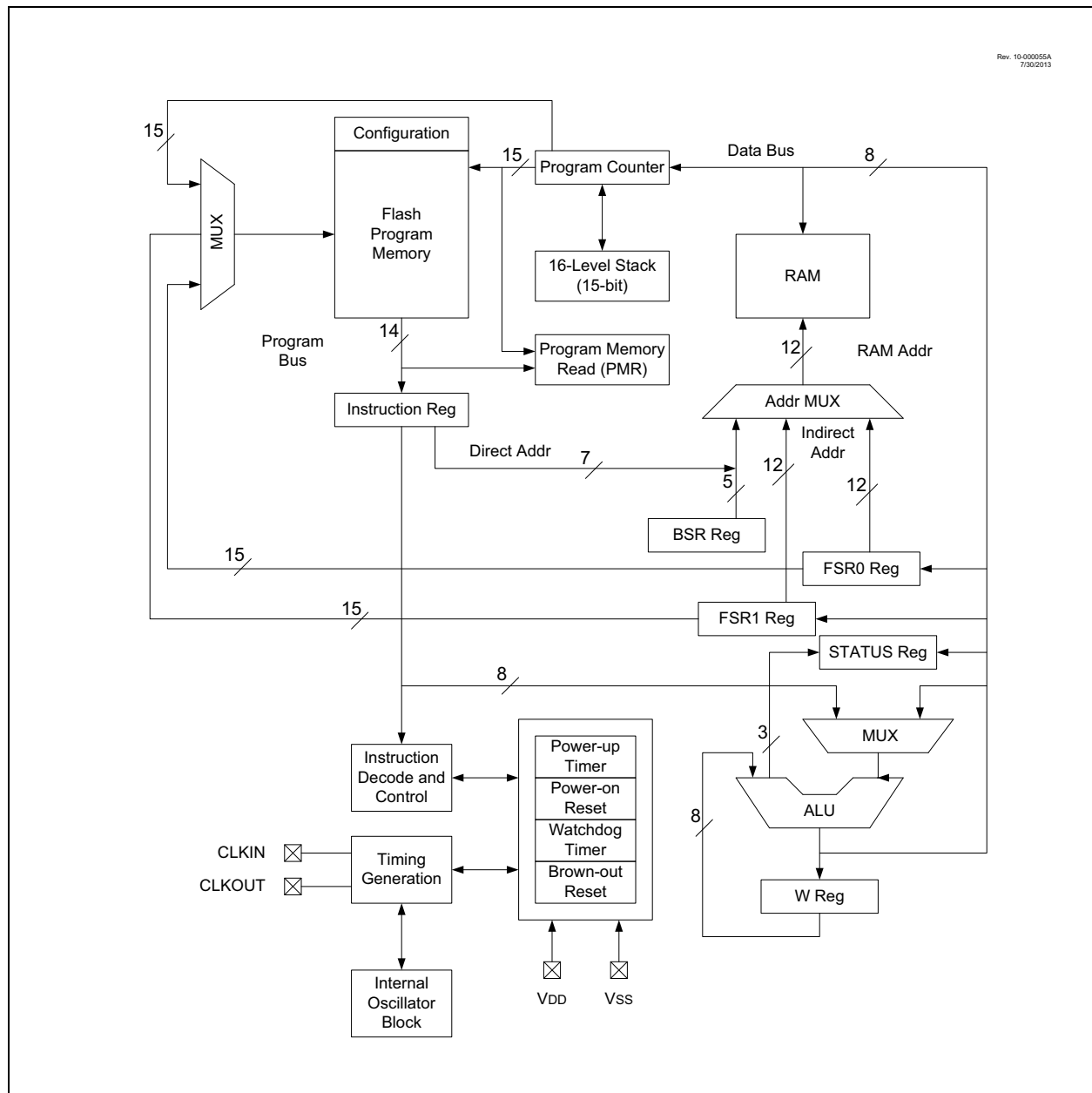
Note 1: Alternate pin function selected with the APFCON register (Register 12-1).

2.0 ENHANCED MID-RANGE CPU

This family of devices contain an enhanced mid-range 8-bit CPU core. The CPU has 49 instructions. Interrupt capability includes automatic context saving. The hardware stack is 16 levels deep and has Overflow and Underflow Reset capability. Direct, Indirect, and Relative Addressing modes are available. Two File Select Registers (FSRs) provide the ability to read program and data memory.

- Automatic Interrupt Context Saving
- 16-level Stack with Overflow and Underflow
- File Select Registers
- Instruction Set

FIGURE 2-1: CORE BLOCK DIAGRAM



2.1 Automatic Interrupt Context Saving

During interrupts, certain registers are automatically saved in shadow registers and restored when returning from the interrupt. This saves stack space and user code. See **Section 7.5 “Automatic Context Saving”**, for more information.

2.2 16-Level Stack with Overflow and Underflow

These devices have a hardware stack memory 15 bits wide and 16 words deep. A Stack Overflow or Underflow will set the appropriate bit (STKOVF or STKUNF) in the PCON register, and if enabled, will cause a software Reset. See section **Section 3.5 “Stack”** for more details.

2.3 File Select Registers

There are two 16-bit File Select Registers (FSR). FSRs can access all file registers and program memory, which allows one Data Pointer for all memory. When an FSR points to program memory, there is one additional instruction cycle in instructions using INDF to allow the data to be fetched. General purpose memory can now also be addressed linearly, providing the ability to access contiguous data larger than 80 bytes. There are also new instructions to support the FSRs. See **Section 3.6 “Indirect Addressing”** for more details.

2.4 Instruction Set

There are 49 instructions for the enhanced mid-range CPU to support the features of the CPU. See **Section 27.0 “Instruction Set Summary”** for more details.

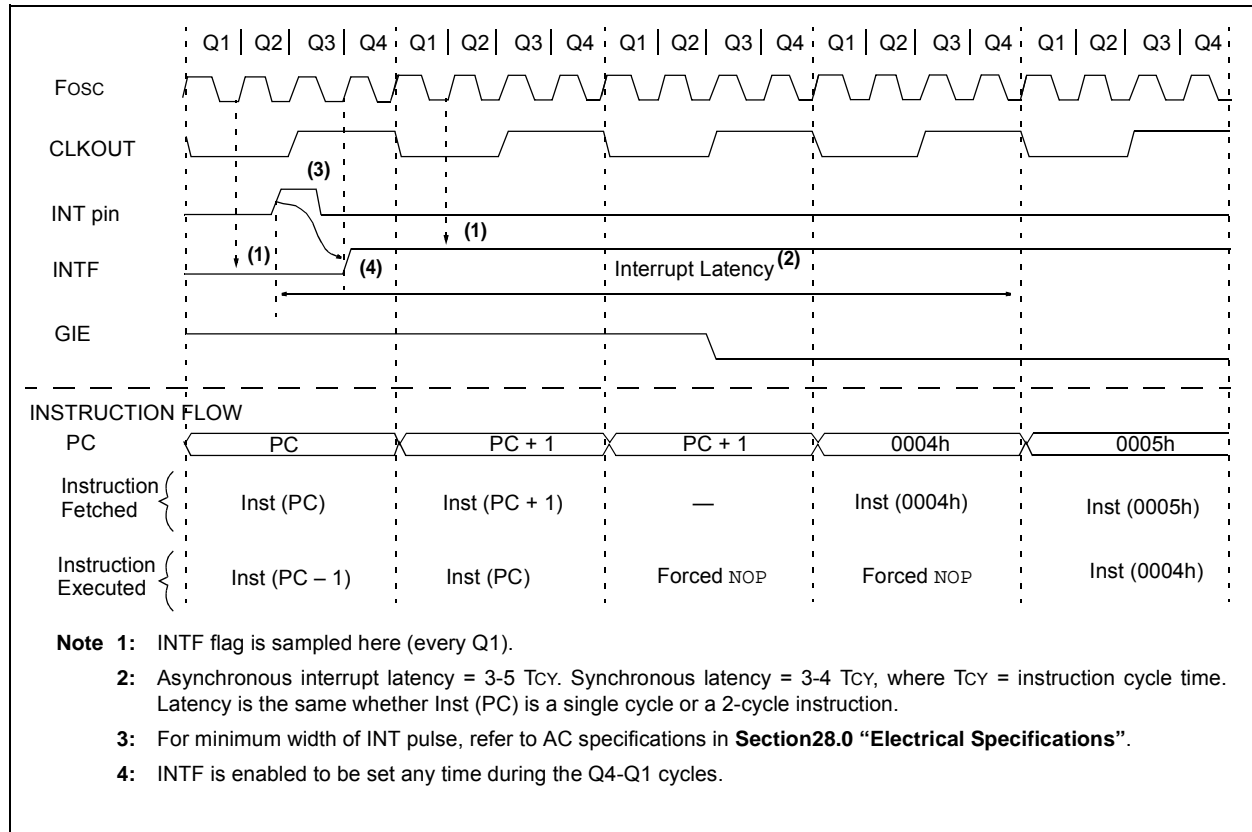
TABLE 3-9: SPECIAL FUNCTION REGISTER SUMMARY (CONTINUED)

Addr	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on POR, BOR	Value on all other Resets
Bank 12											
60Ch to 61Fh	—	Unimplemented								—	—
Bank 13											
68Ch to 690h	—	Unimplemented								—	—
691h	CWG1DBR	—	—	DBR<5:0>						--00 0000	--00 0000
692h	CWG1DBF	—	—	DBF<5:0>						--xx xxxx	--xx xxxx
693h	CWG1AS0	SHUTDOWN	REN	LSBD<1:0>		LSAC<1:0>		—	—	0000 00--	0000 00--
694h	CWG1AS1	—	TMR6AS	TMR4AS	TMR2AS	—	C2AS ⁽⁴⁾	C1AS	INAS	-000 -000	-000 -000
695h	CWG1OCON0	OVRD	OVRC	OVRB	OVRA	STRD	STRC	STRB	STRA	0000 0000	0000 0000
696h	CWG1CON0	EN	LD	—	—	—	MODE<2:0>			00-- -000	00-- -000
697h	CWG1CON1	—	—	IN	—	POLD	POLC	POLB	POLA	--x- 0000	--x- 0000
698h	CWG1OCON1	—	—	—	—	OED	OEC	OEB	OEA	---- 0000	---- 0000
699h	CWG1CLKCON	—	—	—	—	—	—	—	CS	---- ---0	---- ---0
69Ah	CWG1ISM	—	—	—	—	—	IS<2:0>			---- -000	---- -000
69Bh to 6EFh	—	Unimplemented								—	—

Legend: x = unknown, u = unchanged, q = value depends on condition, - = unimplemented, r = reserved. Shaded locations are unimplemented, read as '0'.

- Note** 1: PIC12F1612/16F1613 only.
 2: Unimplemented, read as '1'.
 3: PIC12(L)F1612 only.
 4: PIC16(L)F1613 only.

FIGURE 7-3: INT PIN INTERRUPT TIMING



PIC12(L)F1612/16(L)F1613

8.3 Register Definitions: Voltage Regulator Control

REGISTER 8-1: VREGCON: VOLTAGE REGULATOR CONTROL REGISTER⁽¹⁾

U-0	U-0	U-0	U-0	U-0	U-0	R/W-0/0	R/W-1/1
—	—	—	—	—	—	VREGPM	Reserved
bit 7							bit 0

Legend:

R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
u = Bit is unchanged	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	

bit 7-2 **Unimplemented:** Read as '0'

bit 1 **VREGPM:** Voltage Regulator Power Mode Selection bit

- 1 = Low-Power Sleep mode enabled in Sleep⁽²⁾
Draws lowest current in Sleep, slower wake-up
- 0 = Normal Power mode enabled in Sleep⁽²⁾
Draws higher current in Sleep, faster wake-up

bit 0 **Reserved:** Read as '1'. Maintain this bit set.

Note 1: PIC12F1612/16F1613 only.

2: See **Section 28.0 “Electrical Specifications”**.

TABLE 8-1: SUMMARY OF REGISTERS ASSOCIATED WITH POWER-DOWN MODE

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Register on Page
INTCON	GIE	PEIE	TMR0IE	INTE	IOCFIE	TMR0IF	INTF	IOCFIF	82
IOCAF	—	—	IOCAF5	IOCAF4	IOCAF3	IOCAF2	IOCAF1	IOCAF0	148
IOCAN	—	—	IOCAN5	IOCAN4	IOCAN3	IOCAN2	IOCAN1	IOCAN0	148
IOCAP	—	—	IOCAP5	IOCAP4	IOCAP3	IOCAP2	IOCAP1	IOCAP0	148
IOCCP ⁽¹⁾	—	—	IOCCP5	IOCCP4	IOCCP3	IOCCP2	IOCCP1	IOCCP0	148
IOCCN ⁽¹⁾	—	—	IOCCN5	IOCCN4	IOCCN3	IOCCN2	IOCCN1	IOCCN0	148
IOCCF ⁽¹⁾	—	—	IOCCF5	IOCCF4	IOCCF3	IOCCF2	IOCCF1	IOCCF0	148
PIE1	TMR1GIE	ADIE	—	—	—	CCP1IE	TMR2IE	TMR1IE	83
PIE2	—	C2IE ⁽¹⁾	C1IE	—	—	TMR6IE	TMR4IE	CCP2IE	84
PIE3	—	—	CWGIE	ZCDIE	—	—	—	—	85
PIE4	SCANIE	CRCIE	SMT2PWAIE	SMT2PRAIE	SMT2IE	SMT1PWAIE	SMT1PRAIE	SMT1IF	86
PIR1	TMR1GIF	ADIF	—	—	—	CCP1IF	TMR2IF	TMR1IF	87
PIR2	—	C2IF ⁽¹⁾	C1IF	—	—	TMR6IF	TMR4IF	CCP2IF	88
PIR3	—	—	CWGIF	ZCDIF	—	—	—	—	89
PIR4	SCANIF	CRCIF	SMT2PWAIF	SMT2PRAIF	SMT2IF	SMT1PWAIF	SMT1PRAIF	SMT1IF	90
STATUS	—	—	—	$\overline{\text{TO}}$	$\overline{\text{PD}}$	Z	DC	C	21
WDTCON0	—	—	WDTPS<4:0>					SEN	99

Legend: — = unimplemented, read as '0'. Shaded cells are not used in Power-Down mode.

Note 1: PIC16(L)F1613 only.

PIC12(L)F1612/16(L)F1613

10.6 Register Definitions: Flash Program Memory Control

REGISTER 10-1: PMDATL: PROGRAM MEMORY DATA LOW BYTE REGISTER

R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u
PMDAT<7:0>							
bit 7							bit 0

Legend:

R = Readable bit
u = Bit is unchanged
'1' = Bit is set

W = Writable bit
x = Bit is unknown
'0' = Bit is cleared

U = Unimplemented bit, read as '0'
-n/n = Value at POR and BOR/Value at all other Resets

bit 7-0 **PMDAT<7:0>**: Read/write value for Least Significant bits of program memory

REGISTER 10-2: PMDATH: PROGRAM MEMORY DATA HIGH BYTE REGISTER

U-0	U-0	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u
PMDAT<13:8>							
bit 7							bit 0

Legend:

R = Readable bit
u = Bit is unchanged
'1' = Bit is set

W = Writable bit
x = Bit is unknown
'0' = Bit is cleared

U = Unimplemented bit, read as '0'
-n/n = Value at POR and BOR/Value at all other Resets

bit 7-6 **Unimplemented**: Read as '0'

bit 5-0 **PMDAT<13:8>**: Read/write value for Most Significant bits of program memory

REGISTER 10-3: PMADRL: PROGRAM MEMORY ADDRESS LOW BYTE REGISTER

R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0
PMADR<7:0>							
bit 7							bit 0

Legend:

R = Readable bit
u = Bit is unchanged
'1' = Bit is set

W = Writable bit
x = Bit is unknown
'0' = Bit is cleared

U = Unimplemented bit, read as '0'
-n/n = Value at POR and BOR/Value at all other Resets

bit 7-0 **PMADR<7:0>**: Specifies the Least Significant bits for program memory address

REGISTER 10-4: PMADRH: PROGRAM MEMORY ADDRESS HIGH BYTE REGISTER

U-1	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0
—(1)	PMADR<14:8>						
bit 7							bit 0

Legend:

R = Readable bit
u = Bit is unchanged
'1' = Bit is set

W = Writable bit
x = Bit is unknown
'0' = Bit is cleared

U = Unimplemented bit, read as '0'
-n/n = Value at POR and BOR/Value at all other Resets

bit 7 **Unimplemented**: Read as '1'

bit 6-0 **PMADR<14:8>**: Specifies the Most Significant bits for program memory address

Note 1: Unimplemented, read as '1'.

PIC12(L)F1612/16(L)F1613

REGISTER 10-6: PMCON2: PROGRAM MEMORY CONTROL 2 REGISTER

W-0/0	W-0/0	W-0/0	W-0/0	W-0/0	W-0/0	W-0/0	W-0/0
Program Memory Control Register 2							
bit 7				bit 0			

Legend:

R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
S = Bit can only be set	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	

bit 7-0

Flash Memory Unlock Pattern bits

To unlock writes, a 55h must be written first, followed by an AAh, before setting the WR bit of the PMCON1 register. The value written to this register is used to unlock the writes. There are specific timing requirements on these writes.

TABLE 10-3: SUMMARY OF REGISTERS ASSOCIATED WITH FLASH PROGRAM MEMORY

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Register on Page
INTCON	GIE	PEIE	TMR0IE	INTE	IOCIE	TMR0IF	INTF	IOCIF	82
PMCON1	— ⁽¹⁾	CFGS	LWLO	FREE	WRERR	WREN	WR	RD	117
PMCON2	Program Memory Control Register 2								118
PMADRL	PMADRL<7:0>								116
PMADRH	— ⁽¹⁾	PMADRH<6:0>							116
PMDATL	PMDATL<7:0>								116
PMDATH	—	—	PMDATH<5:0>						116

Legend: — = unimplemented location, read as '0'. Shaded cells are not used by Flash program memory.

Note 1: Unimplemented, read as '1'.

TABLE 10-4: SUMMARY OF CONFIGURATION WORD WITH FLASH PROGRAM MEMORY

Name	Bits	Bit -/7	Bit -/6	Bit 13/5	Bit 12/4	Bit 11/3	Bit 10/2	Bit 9/1	Bit 8/0	Register on Page
CONFIG1	13:8	—	—	—	—	CLKOUTEN	BOREN<1:0>		—	52
	7:0	CP	MCLRE	PWRTE	—	—	—	FOSC<1:0>		
CONFIG2	13:8	—	—	LVP	DEBUG	LPBOR	BORV	STVREN	PLLEN	53
	7:0	ZCD	—	—	—	—	—	WRT<1:0>		
CONFIG3	13:8	—	—	WDTCCS<2:0>			WDTCCWS<2:0>			53
	7:0	—	WDTE<1:0>		WDTCCPS<4:0>					

Legend: — = unimplemented location, read as '0'. Shaded cells are not used by Flash program memory.

PIC12(L)F1612/16(L)F1613

REGISTER 12-8: SLRCONA: PORTA SLEW RATE CONTROL REGISTER

U-0	U-0	R/W-1/1	R/W-1/1	U-0	R/W-1/1	R/W-1/1	R/W-1/1
—	—	SLRA5	SLRA4	—	SLRA2	SLRA1	SLRA0
bit 7				bit 0			

Legend:

R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
u = Bit is unchanged	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	

- bit 7-6 **Unimplemented:** Read as '0'
- bit 5-4 **SLRA<5:4>:** PORTA Slew Rate Enable bits
For RA<5:4> pins, respectively
1 = Port pin slew rate is limited
0 = Port pin slews at maximum rate
- bit 3 **Unimplemented:** Read as '0'
- bit 2-0 **SLRA<2:0>:** PORTA Slew Rate Enable bits
For RA<2:0> pins, respectively
1 = Port pin slew rate is limited
0 = Port pin slews at maximum rate

REGISTER 12-9: INLVLA: PORTA INPUT LEVEL CONTROL REGISTER

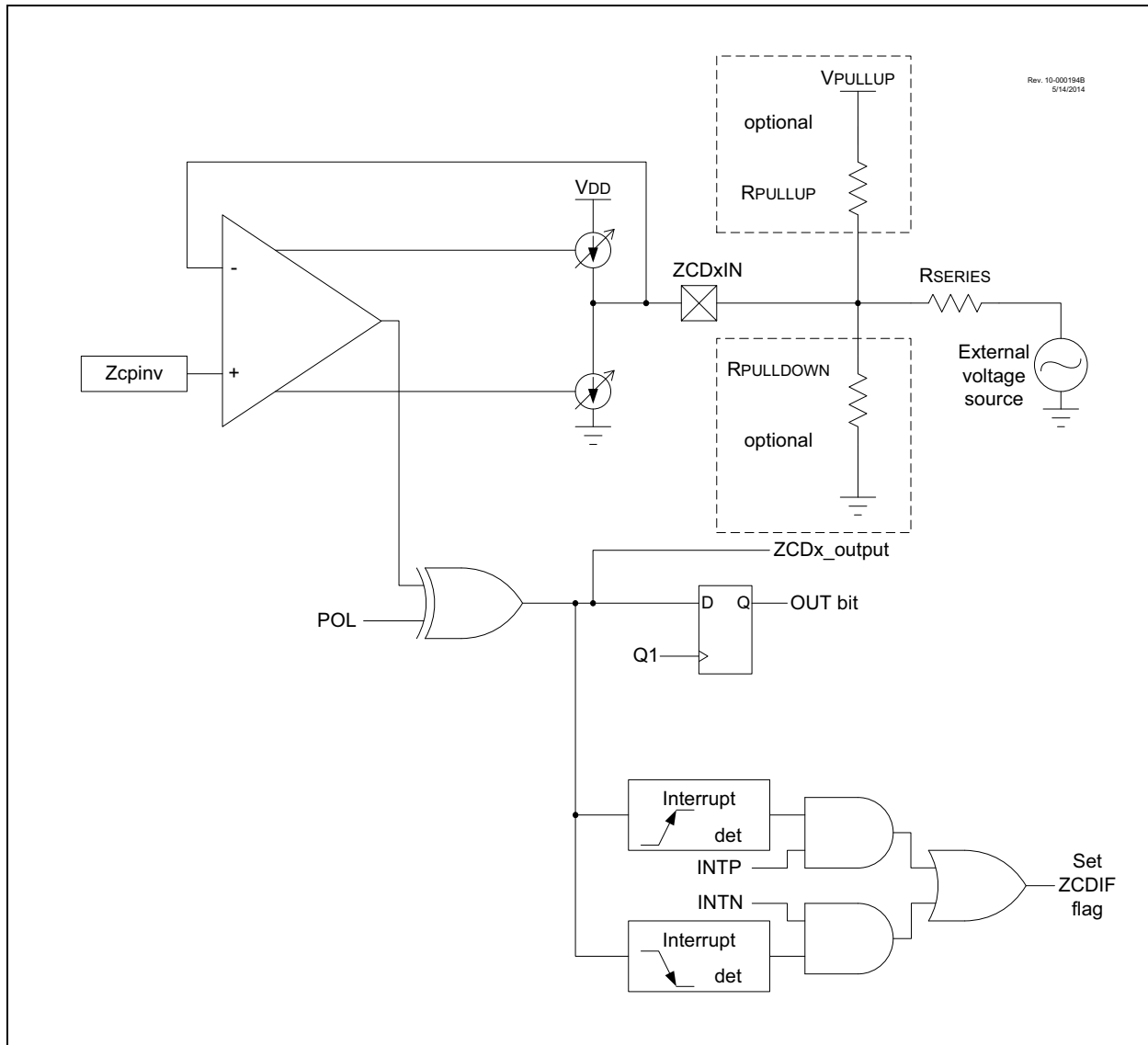
U-0	U-0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0
—	—	INLVLA5	INLVLA4	INLVLA3	INLVLA2	INLVLA1	INLVLA0
bit 7				bit 0			

Legend:

R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
u = Bit is unchanged	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	

- bit 7-6 **Unimplemented:** Read as '0'
- bit 5-0 **INLVLA<5:0>:** PORTA Input Level Select bits
For RA<5:0> pins, respectively
1 = ST input used for PORT reads and interrupt-on-change
0 = TTL input used for PORT reads and interrupt-on-change

FIGURE 19-2: SIMPLIFIED ZCD BLOCK DIAGRAM



The pull-up and pull-down resistor values are significantly affected by small variations of V_{CPINV} . Measuring V_{CPINV} can be difficult, especially when the waveform is relative to V_{DD} . However, by combining Equations 19-2 and 19-3, the resistor value can be determined from the time difference between the ZCDx_output high and low periods. Note that the time difference, ΔT , is $4 \cdot T_{OFFSET}$. The equation for determining the pull-up and pull-down resistor values from the high and low ZCDx_output periods is shown in Equation 19-4. The ZCDx_output signal can be directly observed on the ZCDxOUT pin by setting the ZCDxOE bit.

EQUATION 19-4:

$$R = R_{SERIES} \left(\frac{V_{BIAS}}{V_{PEAK} \left(\sin \left(\pi Freq \frac{(\Delta T)}{2} \right) \right)} - 1 \right)$$

R is pull-up or pull-down resistor.

V_{BIAS} is V_{PULLUP} when R is pull-up or V_{DD} when R is pull-down.

ΔT is the ZCDxOUT high and low period difference.

19.6 Handling VPEAK variations

If the peak amplitude of the external voltage is expected to vary, the series resistor must be selected to keep the ZCD current source and sink below the design maximum range of $\pm 600 \mu A$ and above a reasonable minimum range. A general rule of thumb is that the maximum peak voltage can be no more than six times the minimum peak voltage. To ensure that the maximum current does not exceed $\pm 600 \mu A$ and the minimum is at least $\pm 100 \mu A$, compute the series resistance as shown in Equation 19-5. The compensating pull-up for this series resistance can be determined with Equation 19-3 because the pull-up value is independent from the peak voltage.

EQUATION 19-5: SERIES R FOR V RANGE

$$R_{SERIES} = \frac{V_{MAXPEAK} + V_{MINPEAK}}{7 \times 10^{-4}}$$

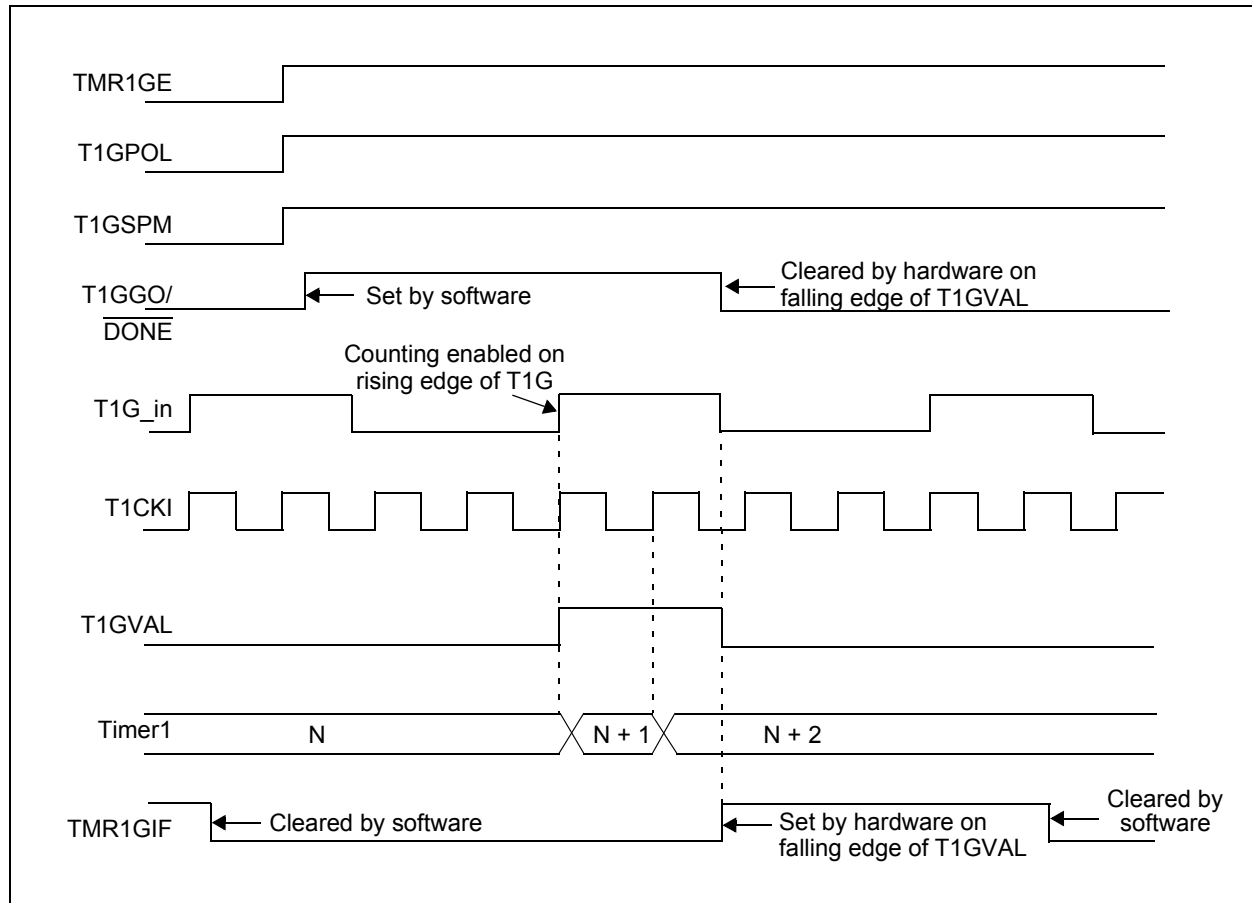
19.7 Operation During Sleep

The ZCD current sources and interrupts are unaffected by Sleep.

19.8 Effects of a Reset

The ZCD circuit can be configured to default to the active or inactive state on Power-On-Reset (POR). When the \overline{ZCD} Configuration bit is cleared, the ZCD circuit will be active at POR. When the \overline{ZCD} Configuration bit is set, the ZCDxEN bit of the ZCDxCON register must be set to enable the ZCD module.

FIGURE 21-5: TIMER1 GATE SINGLE-PULSE MODE



PIC12(L)F1612/16(L)F1613

REGISTER 21-2: T1GCON: TIMER1 GATE CONTROL REGISTER

R/W-0/u	R/W-0/u	R/W-0/u	R/W-0/u	R/W/HC-0/u	R-x/x	R/W-0/u	R/W-0/u
TMR1GE	T1GPOL	T1GTM	T1GSPM	T1GGO/ DONE	T1GVAL	T1GSS<1:0>	
bit 7							bit 0

Legend:

R = Readable bit

W = Writable bit

U = Unimplemented bit, read as '0'

u = Bit is unchanged

x = Bit is unknown

-n/n = Value at POR and BOR/Value at all other Resets

'1' = Bit is set

'0' = Bit is cleared

HC = Bit is cleared by hardware

- bit 7 **TMR1GE:** Timer1 Gate Enable bit
If TMR1ON = 0:
This bit is ignored
If TMR1ON = 1:
1 = Timer1 counting is controlled by the Timer1 gate function
0 = Timer1 counts regardless of Timer1 gate function
- bit 6 **T1GPOL:** Timer1 Gate Polarity bit
1 = Timer1 gate is active-high (Timer1 counts when gate is high)
0 = Timer1 gate is active-low (Timer1 counts when gate is low)
- bit 5 **T1GTM:** Timer1 Gate Toggle Mode bit
1 = Timer1 Gate Toggle mode is enabled
0 = Timer1 Gate Toggle mode is disabled and toggle flip-flop is cleared
Timer1 gate flip-flop toggles on every rising edge.
- bit 4 **T1GSPM:** Timer1 Gate Single-Pulse Mode bit
1 = Timer1 gate Single-Pulse mode is enabled and is controlling Timer1 gate
0 = Timer1 gate Single-Pulse mode is disabled
- bit 3 **T1GGO/DONE:** Timer1 Gate Single-Pulse Acquisition Status bit
1 = Timer1 gate single-pulse acquisition is ready, waiting for an edge
0 = Timer1 gate single-pulse acquisition has completed or has not been started
- bit 2 **T1GVAL:** Timer1 Gate Value Status bit
Indicates the current state of the Timer1 gate that could be provided to TMR1H:TMR1L.
Unaffected by Timer1 Gate Enable (TMR1GE).
- bit 0 **T1GSS<1:0>:** Timer1 Gate Source Select bits
11 = Comparator 2 optionally synchronized output (C2_OUT_sync)
10 = Comparator 1 optionally synchronized output (C1_OUT_sync)
01 = Timer0 overflow output (T0_overflow)
00 = Timer1 gate pin (T1G)

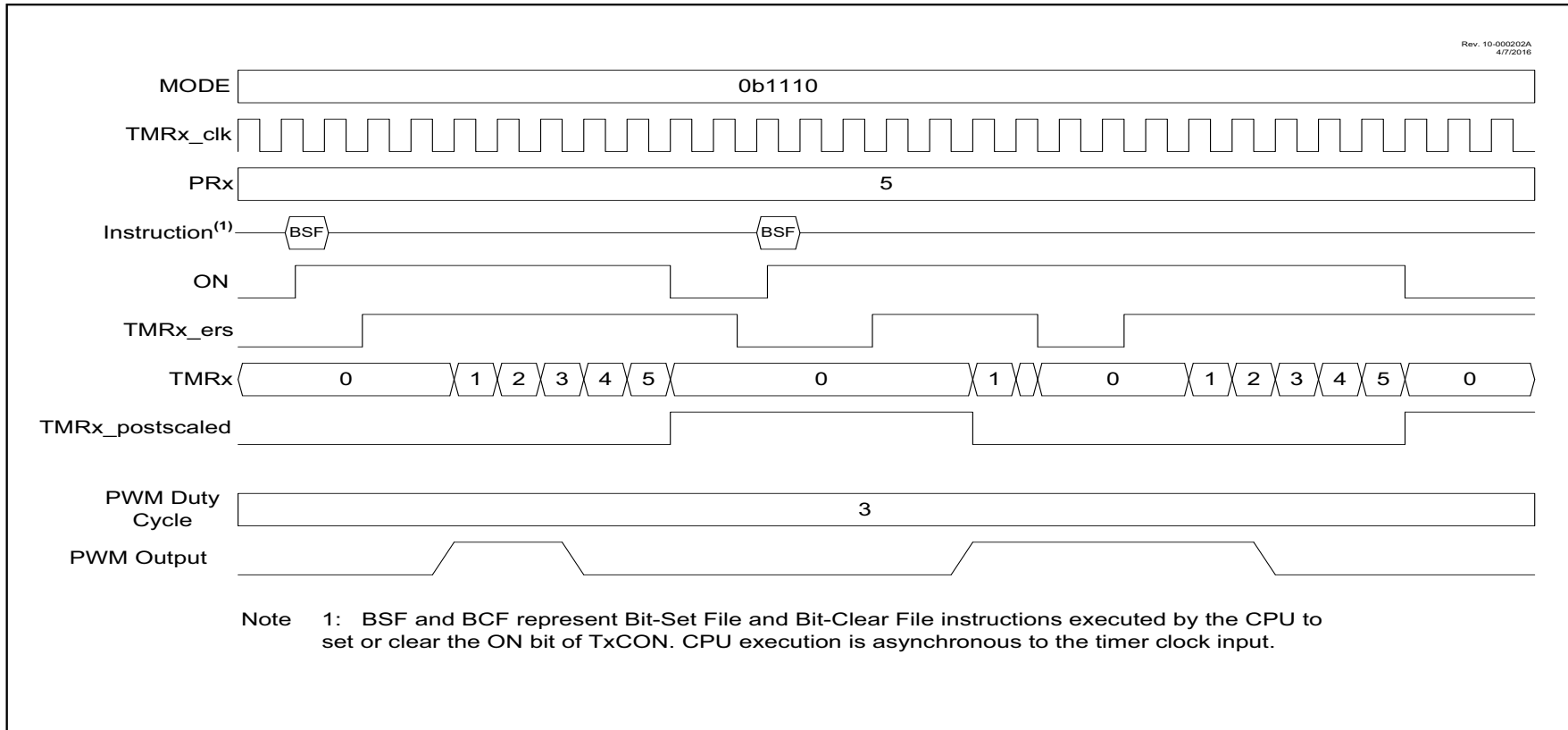
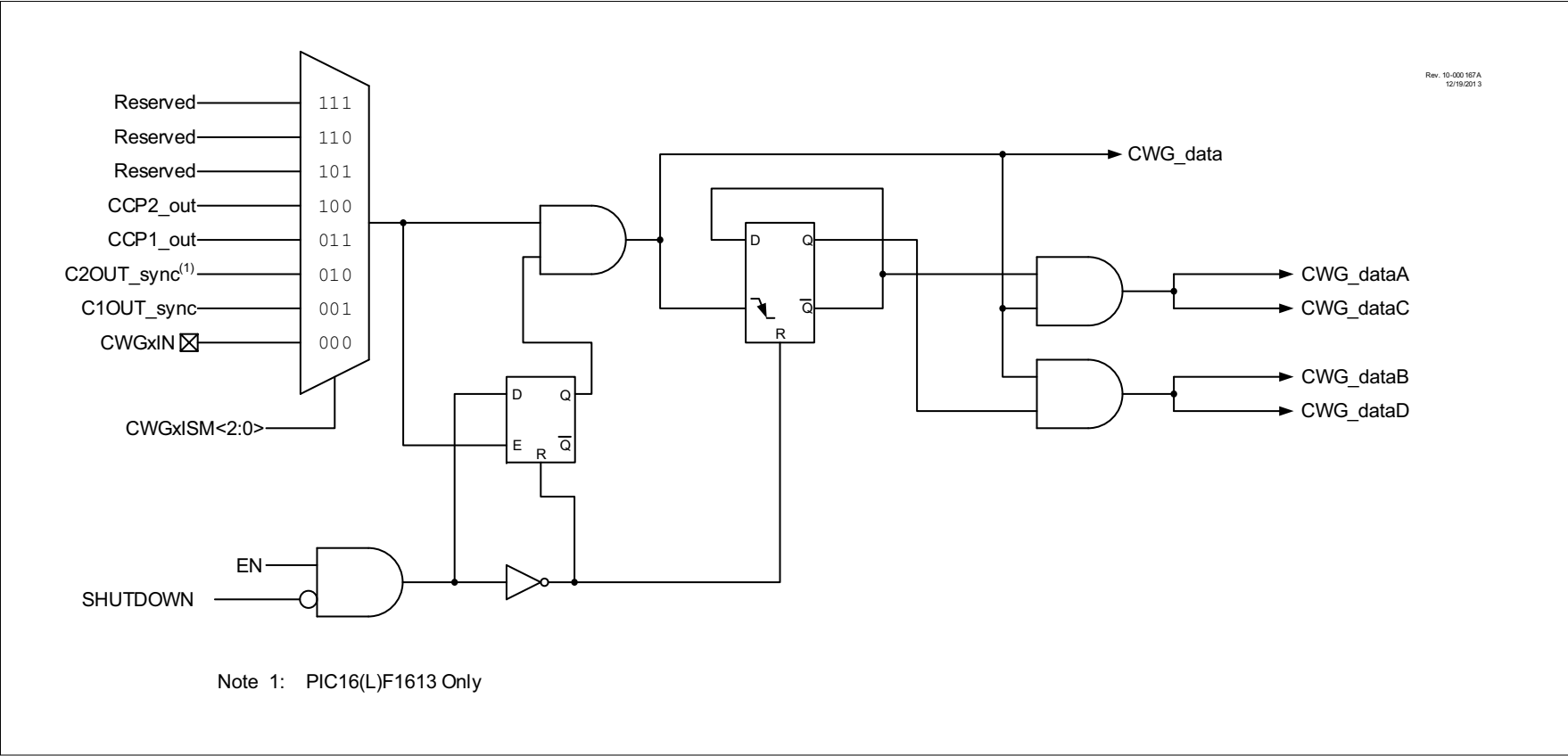
FIGURE 22-11: LEVEL-TRIGGERED HARDWARE LIMIT ONE-SHOT MODE TIMING DIAGRAM

FIGURE 24-2: SIMPLIFIED CWG BLOCK DIAGRAM (PUSH-PULL MODE)



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12/19/2013

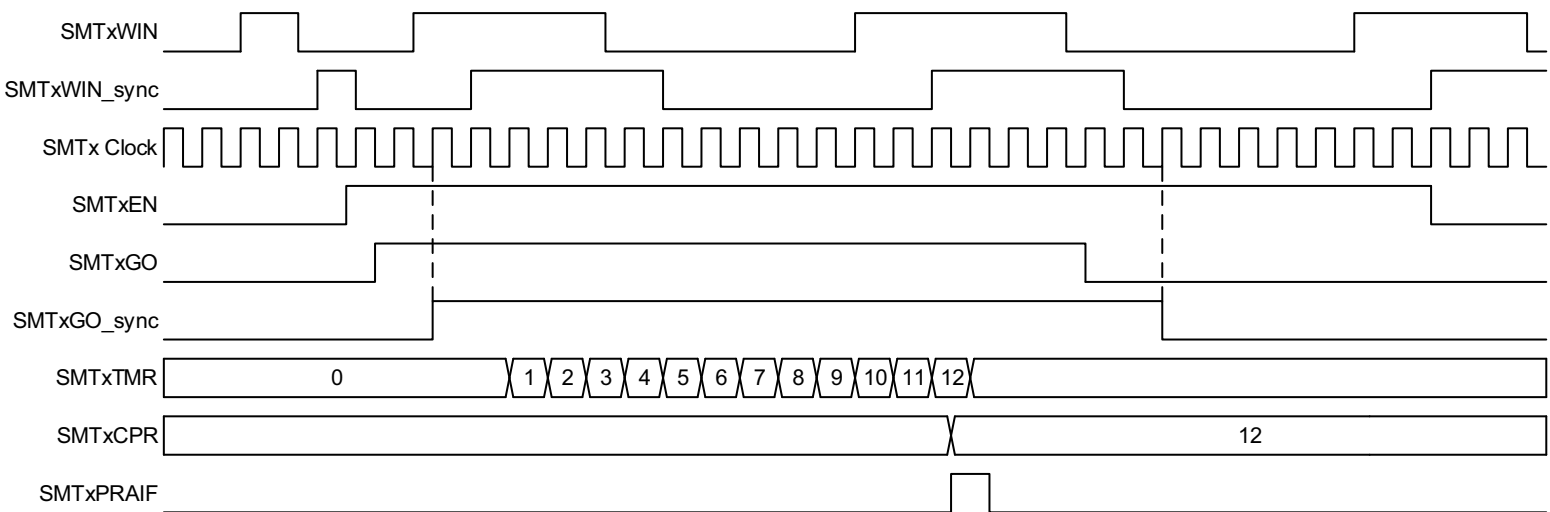


FIGURE 25-11: WINDOWED MEASURE MODE SINGLE ACQUISITION TIMING DIAGRAM

25.6.6 GATED WINDOW MEASURE MODE

This mode measures the duty cycle of the SMTx_signal input over a known input window. It does so by incrementing the timer on each pulse of the clock signal while the SMTx_signal input is high, updating the SMTxCPR register and resetting the timer on every rising edge of the SMTWINx input after the first. See Figure 25-12 and Figure 25-13.

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TABLE 28-5: MEMORY PROGRAMMING SPECIFICATIONS

Standard Operating Conditions (unless otherwise stated)							
Param. No.	Sym.	Characteristic	Min.	Typ†	Max.	Units	Conditions
Program Memory Programming Specifications							
D110	VIHH	Voltage on $\overline{\text{MCLR}}$ /VPP pin	8.0	—	9.0	V	(Note 2)
D111	IDDP	Supply Current during Programming	—	—	10	mA	
D112	VBE	VDD for Bulk Erase	2.7	—	VDDMAX	V	
D113	VPEW	VDD for Write or Row Erase	VDDMIN	—	VDDMAX	V	
D114	IPPPGM	Current on $\overline{\text{MCLR}}$ /VPP during Erase/Write	—	1.0	—	mA	
D115	IDDPGM	Current on VDD during Erase/Write	—	5.0	—	mA	
Program Flash Memory							
D121	EP	Cell Endurance	10K	—	—	E/W	-40°C ≤ TA ≤ +85°C (Note 1)
D122	VPRW	VDD for Read/Write	VDDMIN	—	VDDMAX	V	
D123	TIW	Self-timed Write Cycle Time	—	2	2.5	ms	Provided no other specifications are violated
D124	TRETD	Characteristic Retention	—	40	—	Year	
D125	EHEFC	High-Endurance Flash Cell	100K	—	—	E/W	0°C ≤ TA ≤ +60°C, lower byte last 128 addresses

† Data in "Typ" column is at 3.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

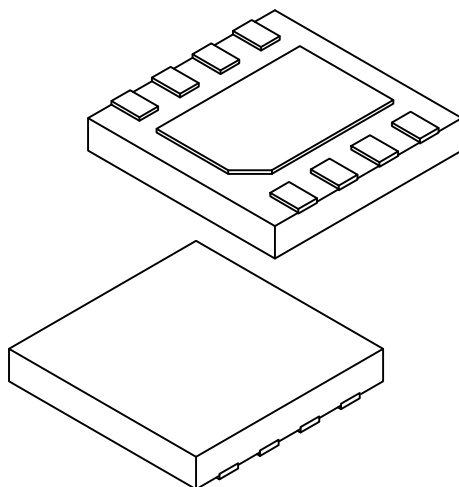
Note 1: Self-write and Block Erase.

2: Required only if single-supply programming is disabled.

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8-Lead Ultra Thin Plastic Dual Flat, No Lead Package (RF) - 3x3x0.50 mm Body [UDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Terminals	N	8		
Pitch	e	0.65 BSC		
Overall Height	A	0.45	0.50	0.55
Standoff	A1	0.00	0.02	0.05
Terminal Thickness	A3	0.065 REF		
Overall Width	E	3.00 BSC		
Exposed Pad Width	E2	1.40	1.50	1.60
Overall Length	D	3.00 BSC		
Exposed Pad Length	D2	2.20	2.30	2.40
Terminal Width	b	0.25	0.30	0.35
Terminal Length	L	0.35	0.45	0.55
Terminal-to-Exposed-Pad	K	0.20	-	-

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Package is saw singulated
3. Dimensioning and tolerancing per ASME Y14.5M

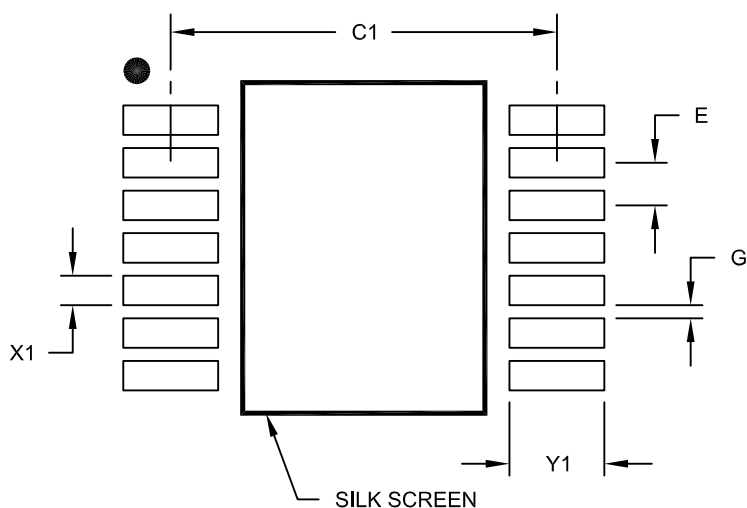
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

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14-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E	0.65 BSC		
Contact Pad Spacing	C1		5.90	
Contact Pad Width (X14)	X1			0.45
Contact Pad Length (X14)	Y1			1.45
Distance Between Pads	G	0.20		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2087A